

450V NPN HIGH VOLTAGE POWER TRANSISTOR IN TO92

Features

- $BV_{CEO} > 450V$
- $BV_{CES} > 800V$
- $BV_{EBO} > 9V$
- $I_C = 0.8A$ High Continuous Collector Current
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

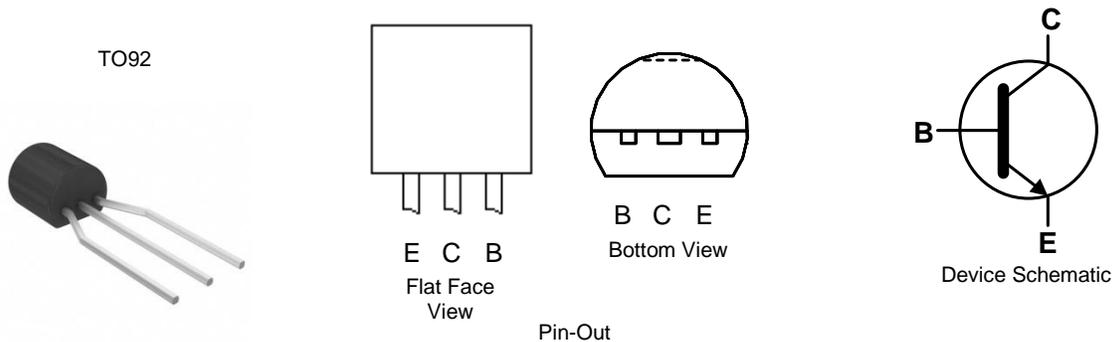
Applications

Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

Mechanical Data

- Case: TO92
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish; Solderable per MIL-STD-202, Method 208 e3
- Weight: TO92: 200mg (Approximate)

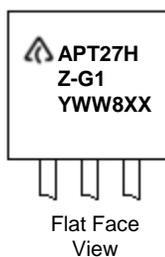


Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT27HZTR-G1	TO92 (Joggled Legs)	APT27HZ-G1	2,000 Taped, per Ammo Box

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



- \triangle = Manufacturers' code marking
- APT27HZ-G1 = Product Type Marking ID
- YWW = Date Code Marking
e.g 312 = Year 2013, Week 12
- 8 = Assembly site code
- XX = Batch Number

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage ($V_{BE} = 0\text{V}$)	V_{CES}	800	V
Collector-Emitter Voltage	V_{CEO}	450	V
Emitter-Base Voltage	V_{EBO}	9	V
Continuous Collector Current	I_C	0.8	A
Peak Pulse Collector Current	I_{CM}	1.6	A
Continuous Base Current	I_B	0.4	A
Peak Pulse Base Current	I_{BM}	0.8	A

Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

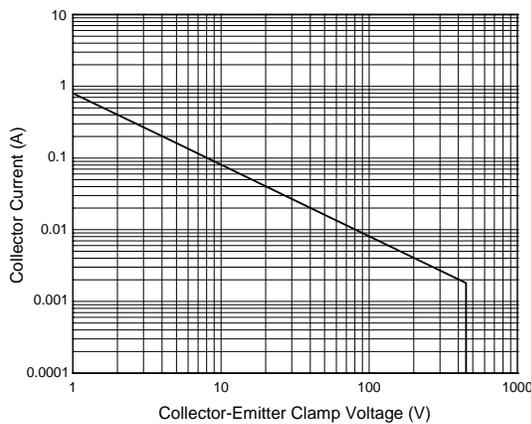
Characteristic	Symbol	Value	Unit
Power Dissipation	P_D	0.8	W
Thermal Resistance, Junction to Ambient Air	$R_{\theta JA}$	156.25	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

ESD Ratings (Note 5)

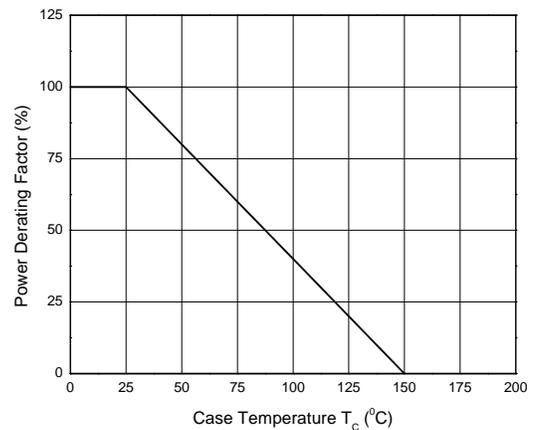
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Area and Derating Information (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



Safe Operating Areas



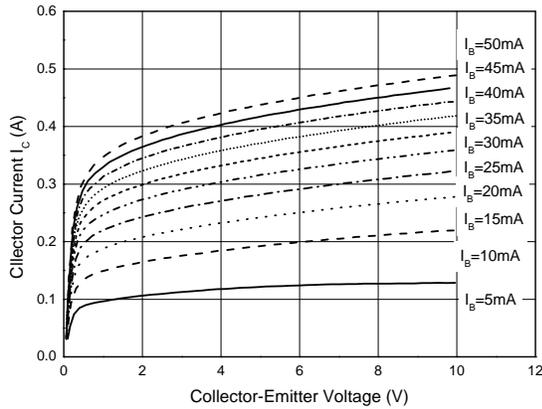
Power Derating Curve

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

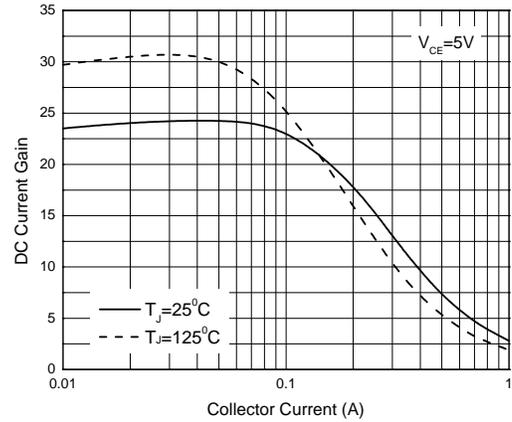
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV_{CES}	800	—	—	V	$I_C = 100\mu\text{A}$, $V_{BE} = 0\text{V}$
Collector-Emitter Breakdown Voltage	BV_{CEO}	450	—	—	V	$I_C = 100\mu\text{A}$
Emitter-Base Breakdown Voltage	BV_{EBO}	9	—	—	V	$I_E = 100\mu\text{A}$
Collector Cutoff Current	I_{CEV}	—	—	10	μA	$V_{CE} = 800\text{V}$, $V_{BE} = -1.5\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	—	—	0.5	V	$I_C = 200\text{mA}$, $I_B = 40\text{mA}$
DC Current Transfer Static Ratio (Note 6)	h_{FE}	15 6	23 15	40 30	—	$I_C = 100\text{mA}$, $V_{CE} = 10\text{V}$ $I_C = 300\text{mA}$, $V_{CE} = 10\text{V}$

Note: 6. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

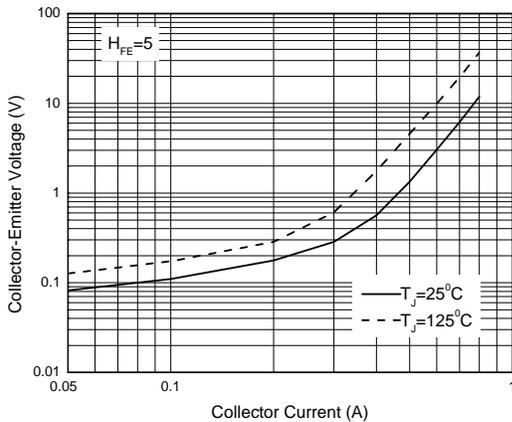
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



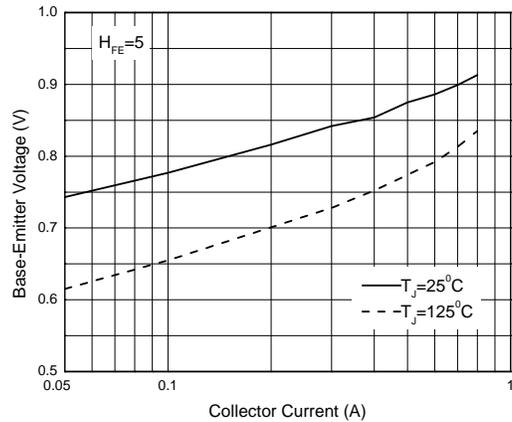
Static Characteristics



DC Current Gain



Collector-Emitter Saturation Region

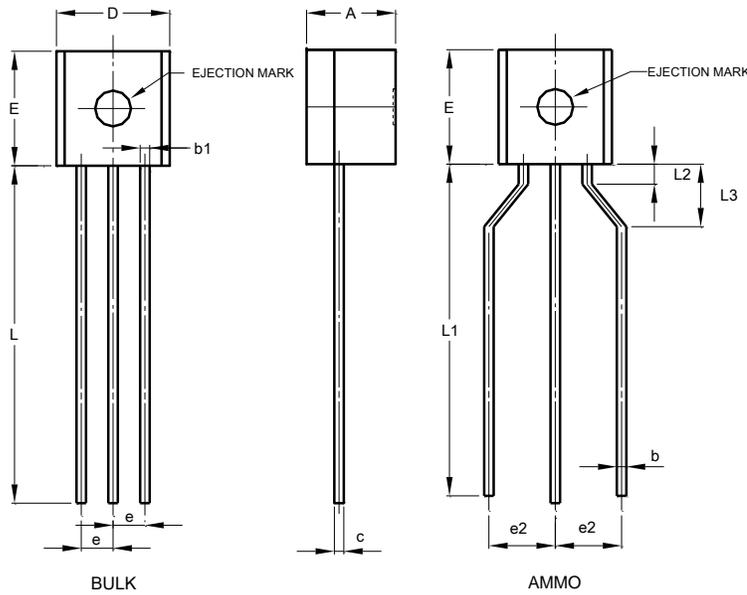


Base-Emitter Saturation Voltage

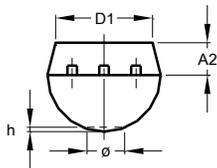
Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

(1) Package Type: T092 Type C



T092 Type C			
Dim	Min	Max	Typ
A	3.30	3.70	-
A2	1.10	1.40	-
b	0.38	0.55	-
c	0.36	0.51	-
D	4.40	4.70	-
D1	3.430	-	-
E	4.30	4.70	-
e	-	-	1.27
e2	2.440	2.640	-
h	0.00	0.38	-
L	14.10	14.50	-
L1	12.50	14.50	-
L3	2.50	3.50	-
ø	-	1.60	-
All Dimensions in mm			



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

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